

Isc N-Channel MOSFET Transistor

STW18N65M5

FEATURES

- Higher V_{DSS} rating
- · Excellent switching performance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

· Switching applications

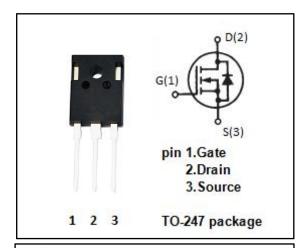


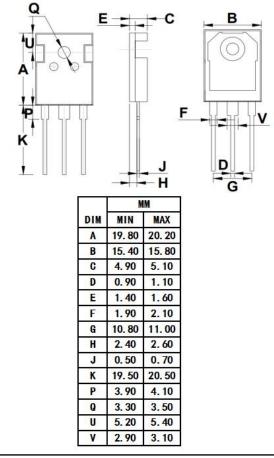
ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|-----------|--------------|
| V _{DSS} | Drain-Source Voltage | 650 | V |
| V _{GSS} | Gate-Source Voltage | ±25 | V |
| l _D | Drain Current-Continuous@T _C =25°C T _C =100°C | 15 9.4 | А |
| Ірм | Drain Current-Single Pulsed | 60 | А |
| P _D | Total Dissipation | 110 | W |
| Tj | Operating Junction Temperature -55~150 | | $^{\circ}$ C |
| T _{stg} | Storage Temperature -55~ | | $^{\circ}$ |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|-----------|------------------------------------|------|------|
| Rth(ch-c) | Channel-to-case thermal resistance | 1.14 | °C/W |





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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | MAX | UNIT |
|---------------------|--------------------------------|---|-----|-----|----------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D = 1mA | 650 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =±25V; I _D =0.25mA | 3 | | 5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D =7.5A | | | 220 | mΩ |
| lgss | Gate-Source Leakage Current | V _{GS} = ±25V;V _{DS} = 0V | | | ±0.1 | μА |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} = 650V; V _{GS} = 0V; T _J =25°C T _J =125°C | | | 1 100 | μА |
| V _{SDF} | Diode forward voltage | I _{SD} =15A, V _{GS} = 0 V | | | 1.5 | V |

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